

2N5679 2N5680 PNP
2N5681 2N5682 NPN

**COMPLEMENTARY
SILICON POWER TRANSISTORS**



TO-39 CASE



www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N5679, 2N5681 series devices are complementary silicon power transistors, manufactured by the epitaxial planar process, designed for general purpose amplifier and switching applications where high voltages are required.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

	SYMBOL	2N5679 2N5681	2N5680 2N5682	UNITS
Collector-Base Voltage	V_{CBO}	100	120	V
Collector-Emitter Voltage	V_{CEO}	100	120	V
Emitter-Base Voltage	V_{EBO}		4.0	V
Continuous Collector Current	I_C		1.0	A
Continuous Base Current	I_B		0.5	A
Power Dissipation	P_D		1.0	W
Power Dissipation ($T_C=25^\circ\text{C}$)	P_D		10	W
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +200		$^\circ\text{C}$
Thermal Resistance	θ_{JA}		175	$^\circ\text{C/W}$
Thermal Resistance	θ_{JC}		17.5	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_{CBO}	$V_{CB}=\text{Rated } V_{CBO}$		1.0	μA
I_{CEV}	$V_{CE}=\text{Rated } V_{CEO}, V_{EB}=1.5\text{V}$		1.0	μA
I_{CEV}	$V_{CE}=\text{Rated } V_{CEO}, V_{EB}=1.5\text{V}, T_C=150^\circ\text{C}$		1.0	mA
I_{CEO}	$V_{CE}=70\text{V}$ (2N5679, 2N5681)		10	μA
I_{CEO}	$V_{CE}=80\text{V}$ (2N5680, 2N5682)		10	μA
I_{EBO}	$V_{EB}=4.0\text{V}$		1.0	μA
BV_{CEO}	$I_C=10\text{mA}$ (2N5679, 2N5681)	100		V
BV_{CEO}	$I_C=10\text{mA}$ (2N5680, 2N5682)	120		V
$V_{CE(SAT)}$	$I_C=250\text{mA}, I_B=25\text{mA}$		0.6	V
$V_{CE(SAT)}$	$I_C=500\text{mA}, I_B=50\text{mA}$		1.0	V
$V_{CE(SAT)}$	$I_C=1.0\text{A}, I_B=200\text{mA}$		2.0	V
$V_{BE(ON)}$	$V_{CE}=2.0\text{V}, I_C=250\text{mA}$		1.0	V
h_{FE}	$V_{CE}=2.0\text{V}, I_C=250\text{mA}$	40	150	
h_{FE}	$V_{CE}=2.0\text{V}, I_C=1.0\text{A}$	5.0		
h_{fe}	$V_{CE}=1.5\text{V}, I_C=0.2\text{A}, f=1.0\text{kHz}$	40		
f_T	$V_{CE}=10\text{V}, I_C=100\text{mA}, f=10\text{MHz}$	30		MHz
C_{ob}	$V_{CB}=20\text{V}, I_E=0, f=1.0\text{MHz}$		50	pF

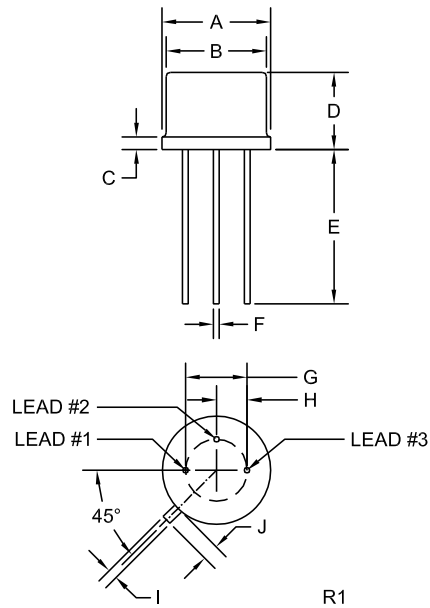
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TO-39 CASE - MECHANICAL OUTLINE



SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A (DIA)	0.335	0.370	8.51	9.40
B (DIA)	0.315	0.335	8.00	8.51
C	-	0.040	-	1.02
D	0.240	0.260	6.10	6.60
E	0.500	-	12.70	-
F (DIA)	0.016	0.021	0.41	0.53
G (DIA)	0.200		5.08	
H	0.100		2.54	
I	0.028	0.034	0.71	0.86
J	0.029	0.045	0.74	1.14

TO-39 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

MARKING: FULL PART NUMBER

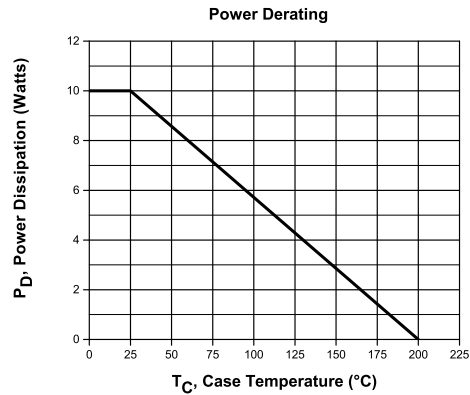
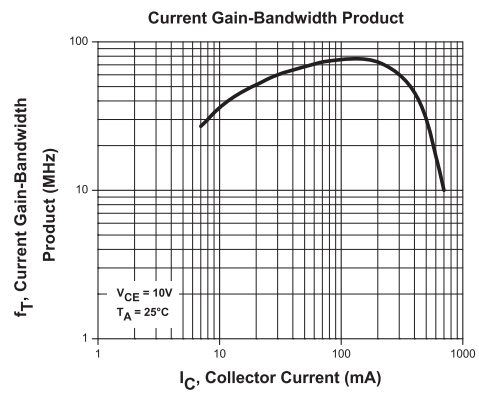
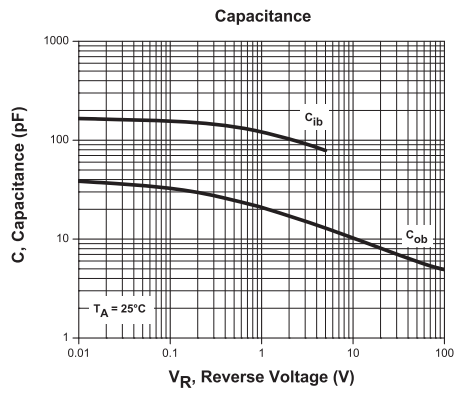
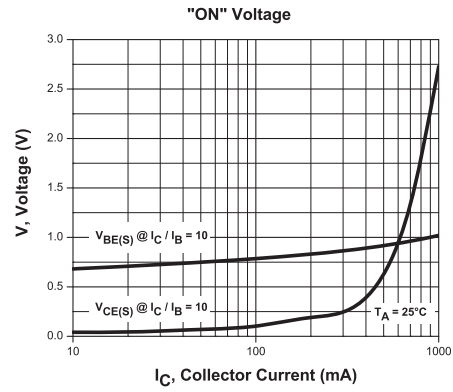
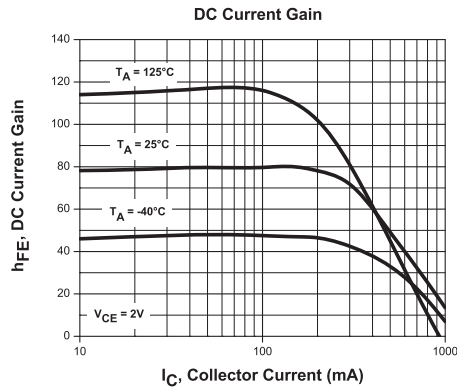
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PNP TYPICAL ELECTRICAL CHARACTERISTICS



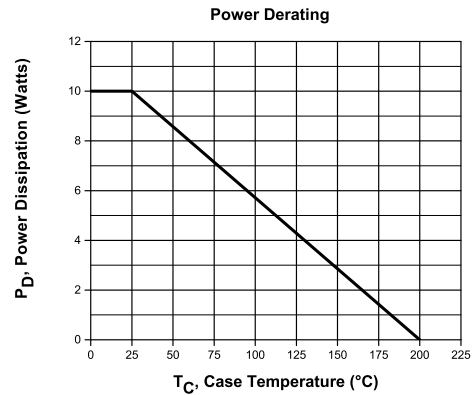
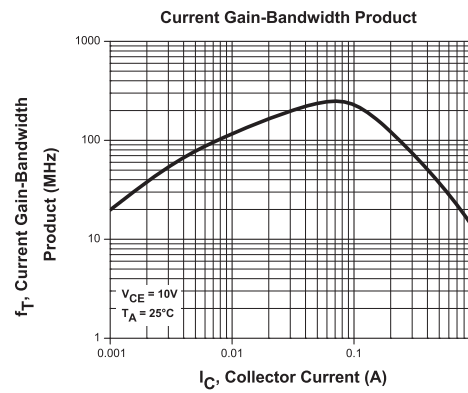
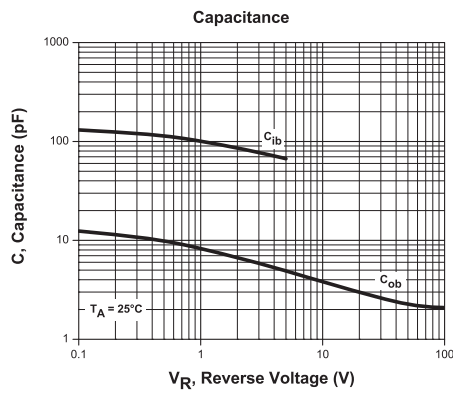
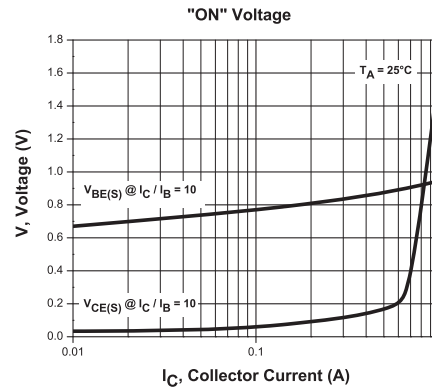
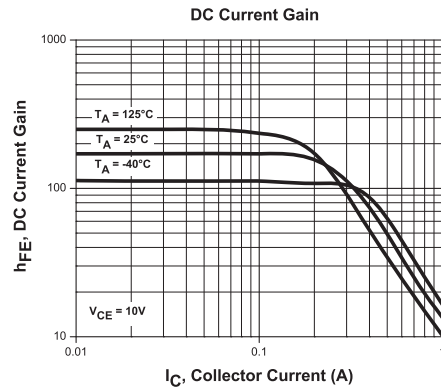
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NPN TYPICAL ELECTRICAL CHARACTERISTICS



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OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix " TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

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<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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